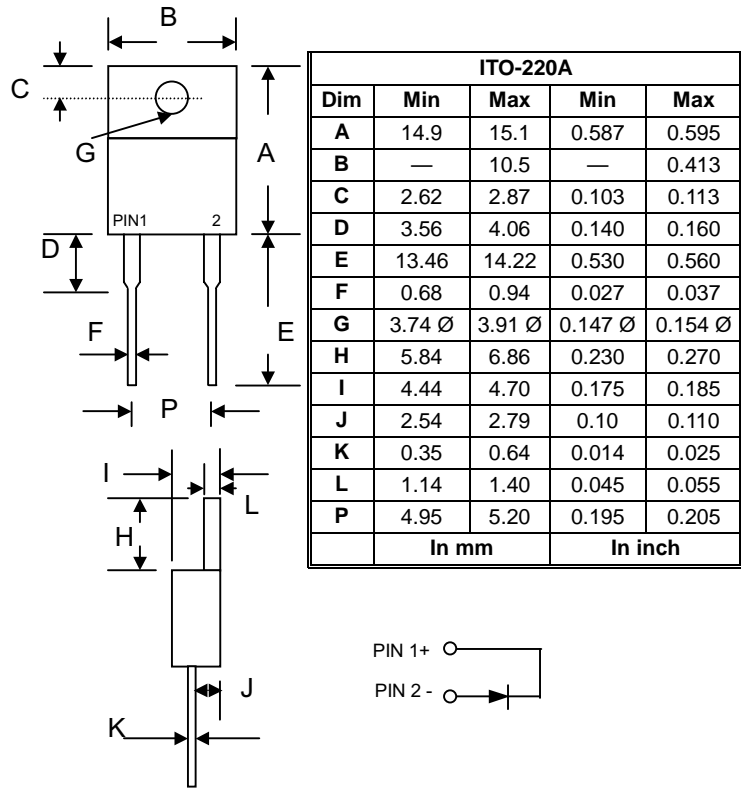


Features

- Glass Passivated Die Construction
- Super-Fast Switching for High Efficiency
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O
- Green Products in Compliance with the RoHS Directive

Mechanical Data

- Case: ITO-220A Full Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Weight: 2.24 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



Maximum Ratings and Electrical Characteristics @ $T_A=25^\circ\text{C}$ unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	Symbol	FESF 8AT-G	FESF 8BT-G	FESF 8CT-G	FESF 8DT-G	FESF 8FT-G	FESF 8GT-G	FESF 8JT-G	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	50	100	150	200	300	400	600	V
Working Peak Reverse Voltage	V_{RWM}								
DC Blocking Voltage	V_R								
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	105	140	210	280	420	V
Average Rectified Output Current @ $T_C = 105^\circ\text{C}$	I_O	8.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	125							A
Forward Voltage @ $I_F = 8.0\text{A}$	V_{FM}	0.95			1.3		1.7		V
Peak Reverse Current @ $T_A = 25^\circ\text{C}$ At Rated DC Blocking Voltage @ $T_A = 100^\circ\text{C}$	I_{RM}	10 400							μA
Reverse Recovery Time (Note 1)	t_{rr}	35			50				nS
Typical Junction Capacitance (Note 2)	C_j	70			50				pF
Operating and Storage Temperature Range	T_j, T_{STG}	-65 to +150							$^\circ\text{C}$

Note: 1. Measured with $I_F = 0.5\text{A}$, $I_R = 1.0\text{A}$, $IRR = 0.25\text{A}$.
2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

Data Sheet 4829, Rev.-

Green Products

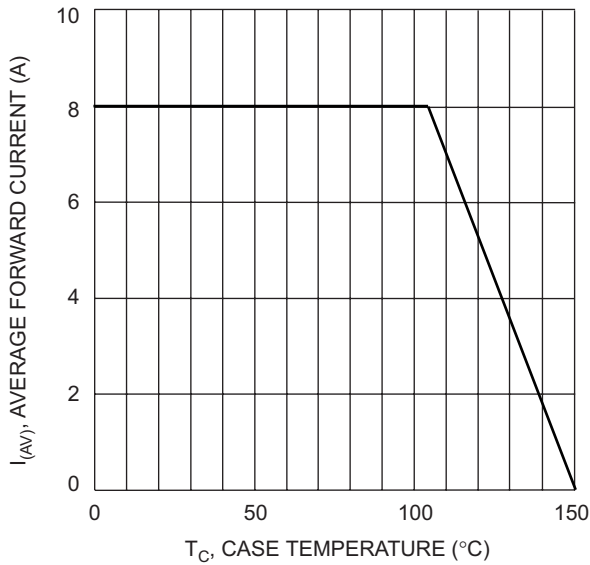


Fig. 1 Forward Current Derating Curve

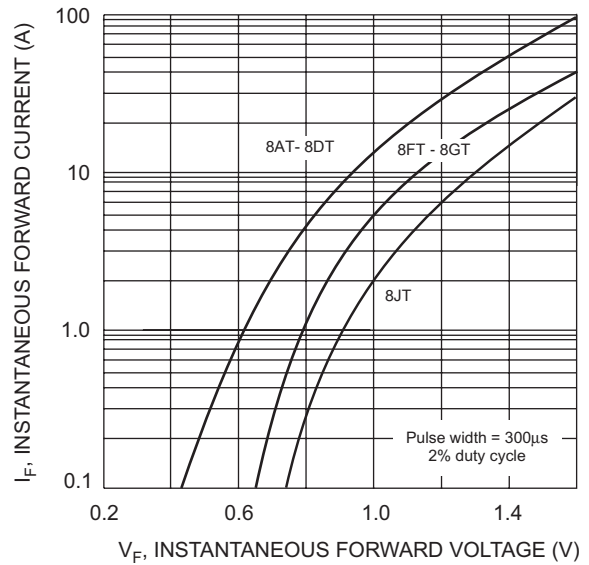


Fig. 2 Typical Forward Characteristics

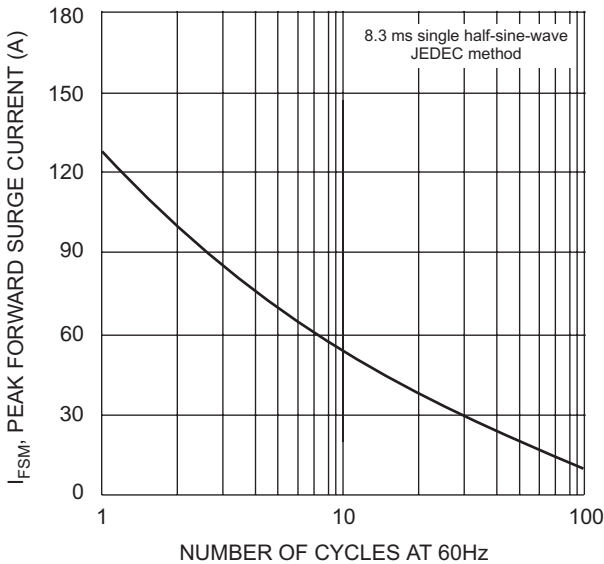


Fig. 3 Max Non-Repetitive Surge Current

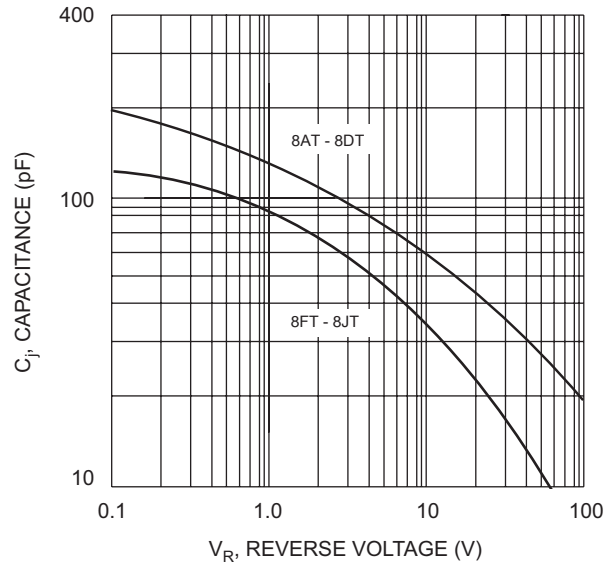


Fig. 4 Typical Junction Capacitance

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